

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

# PA Bell SUPOZ

in re the Application of: Minoru SUZUKI et al. (

Serial No.: 10/014,407

Group Art Unit: Not Yet Assigned

Filed: December 14, 2001

Examiner: Not Yet Assigned

For: SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING

A SEMICONDUCTOR DEVICE

## PRELIMINARY AMENDMENT

Commissioner for Patents Washington, D.C. 20231

January 24, 2002

Sir:

This is a Preliminary Amendment for the above-captioned patent application. Please amend the above-captioned patent application as follows:

## **IN THE SPECIFICATION:**

Please replace the paragraph beginning at page 11, line 14, with the following rewritten paragraph:

Referring to FIG. 1(a), first, a semiconductor substrate 9 consisting of high-resistivity N-type silicon single crystal is prepared. Here, a crystal with a resistivity of  $20\Omega$ cm or more, and less than or equal to  $60\Omega$ cm (less than or equal to  $2X10^{14}$ /cm<sup>3</sup> and greater than or equal to  $7X10^{13}$ /cm<sup>3</sup> in concentration conversions) was used as the semiconductor substrate 9.

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